

SANYO Semiconductors DATA SHEET

Bi-CMOS LSI

LV4910T — Class-D Audio Power Amplifier BTL 2W × 2ch

Overview

LV4910T is a stereo digital amplifier for portable equipment, for example notebook-PC, portable DVD and portable mini-speakers. It is characterized by the use of an original feedback technology to improve sound quality though it is Class-D amplifier, and does not need the LC filter in the output stage.

Features

- D-class high-efficiency amplifier
- Low pop sound at SW changeover
- Differential input type

Functions

- 2W stereo digital power amplifier
- Standby switch
- Mute switch
- Various protective circuits (over-current protective, thermal protective, and under-voltage circuits) incorporated

Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage	V _{CC} max		6	V
Allowable power dissipation	Pd max	as mounted on the substrate	1.05	W
Operating temperature	Topr		-20 to +75	°C
Storage temperature	Tstg		-40 to +150	°C

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Operating Conditions at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Recommended supply voltage	VCC		5	V
Operation supply voltage range	V _{CC} opg		2.5 to 5.5	V
Recommended load resistance	R_{L}	Speaker	4	Ω

Electrical Characteristics Ta = 25°C, $V_{CC} = 5V$, f = 1kHz, $R_L = 4\Omega$

Parameter	O. mah al	Conditions		Ratings		Unit
Parameter	Symbol	Conditions	min	typ	max	Unit
Standby current	Ist	Current at ST ON			1	μΑ
Current at no signal	I _{CCO} 1	At LC filter-less		12	20	mA
Current at Mute	I _{CCO} mute	At Mute of speaker		10	16	mA
Voltage gain	VG	$V_O = 0$ dBm	21	23	25	dB
Channel balance	ΔVG	V _O = 0dBm	-1	0	1	dB
Output power	PO	THD = 10%		2		W
Total harmonic distortion	THD	P _O = 0.5W, DIN AUDIO		0.4	0.7	%
Output noise voltage	V _{NO}	Rg = 0, DIN AUDIO		100	200	μV
Crosstalk	СТ	V _O = 0dBm, TUN 1kHz		-60	-40	dB
Ripple rejection ratio	RR	fr = 100Hz, Vr = -10dBm, TUN 100Hz		-40	-30	dB
Common mode rejection ratio	CMRR	V _O = 0dBm, DIN AUDIO		-60	-40	dB
Mute attenuation value	V _{OFF}	V _O = 0dBm, DIN AUDIO		-80	-70	dB
Oscillation frequency	F _{PWM}			300		kHz
Standby ON voltage sensitivity	VPWROFF	Standby ON start voltage			1	V
Standby OFF voltage sensitivity	V _{PWRON}	Standby OFF start voltage	3			V
Mute ON voltage sensitivity	VMUTEON	Mute ON start voltage			0.5	V
Mute OFF voltage sensitivity	VMUTEOFF	Mute OFF start voltage	2			V

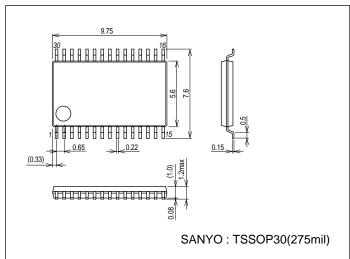
 $^{^{\}star}$ Electrical characteristics vary depending on the substrate layout and selection of external parts.

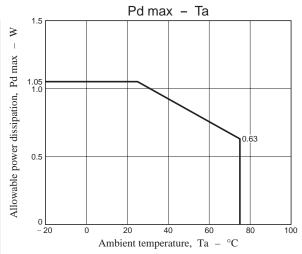
For measurement of the above characteristics, the coil : $22\mu H$ (Toko Kabushiki Kaisha made D63CB) is used.

Package Dimensions

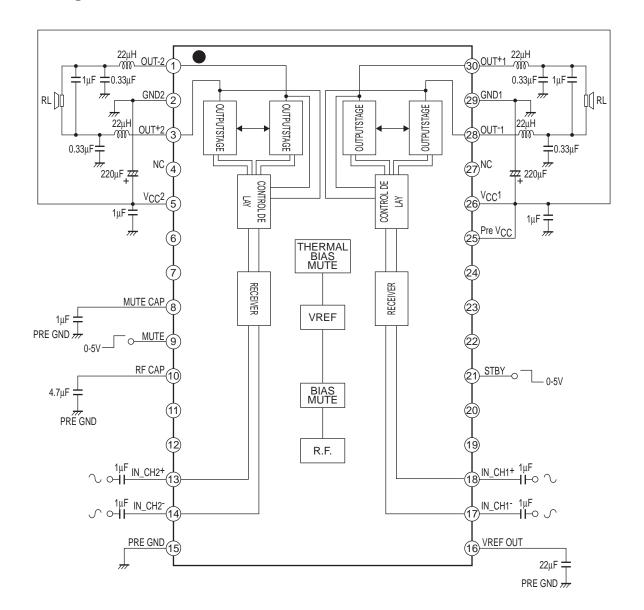
unit: mm (typ)

3259





Block Diagram



LV4910T

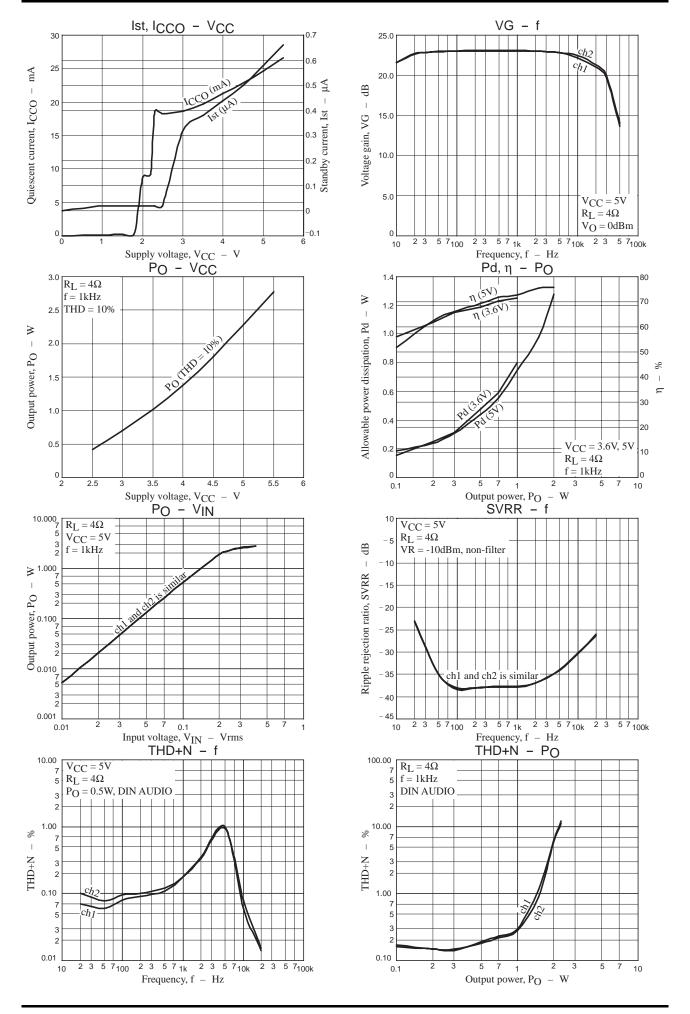
Pin Descriptions

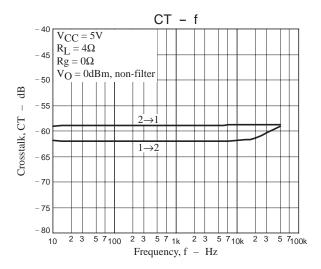
Pin Descriptions							
Pin No.	Pin name	Pin voltage (V)	Pin description	Equivalent circuit			
1	OUT ⁻ 2	2.58	Power outputs	A			
3	OUT+2		·	1			
28	OUT-1						
30	OUT+1			<u> </u>			
				★ ₹⊢			
				<i>m m</i>			
2	GND2	0					
		0	Non-constitut				
4	NC NC	_	Non-connection				
5	V _{CC} 2	5					
6	NC		Non-connection				
7	NC		Non-connection				
8	MUTE CAP	4.9	Connection for the mute switch On/Off impulse noise	^			
			reduction capacitor				
				 			
				↑ ↑ 			
				* \$20kΩ \			
				+ +			
				\$300kΩ			
				\$300K22			
				m m m			
9	MUTE		Mute On/Off switch	A .			
			• 2 to 5.5V : Mute Off	l T I			
			• 0 to 0.7V : Mute On	<u> </u>			
				100kΩ §			
				★ \$20kΩ			
				m m			
10	RF CAP	2.6	Ripple filter reference	A A			
				Δ			
				300Ω 45kΩ W W W			
				★ ≸100kΩ			
				ता ता ता ता			
11	NC		Non-connection				
12	NC		Non-connection				
13	IN_ch2+	2.4	Signal input	 			
14	IN_ch2 ⁻						
17	IN_ch1 ⁻						
18	IN_ch1+			300Ω			
				* ••••			
				30kΩ≨ ↓			
				m m			
	•						

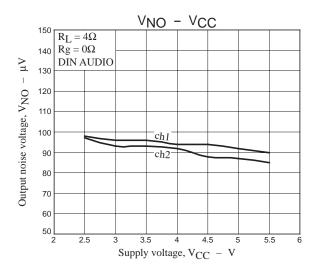
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Pin No.	Pin name	Pin voltage (V)	Pin description	Equivalent circuit			
15	PRE GND	0					
16	VREF OUT	2.55	VREF amplifier reference				
19	NC		Non-connection				
20	NC		Non-connection				
21	STBY		STBY On/Off switch to 1V: Power Off to 5.5V: Power On	\$1kΩ \$20kΩ \$300kΩ \$10kΩ			
22	NC		Non-connection				
23	NC		Non-connection				
24	NC		Non-connection				
25	PRE V _{CC}	5					
26	V _{CC} 1	5					
27	NC		Non-connection				
29	GND1	0					







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